

DATA SHEET

74LVC06A

Hex inverter with open-drain
outputs

Product specification
Supersedes data of 2003 Aug 28

2003 Nov 27

Hex inverter with open-drain outputs

74LVC06A

FEATURES

- 5 V tolerant inputs and outputs (open drain) for interfacing with 5 V logic
- Wide supply voltage range from 1.65 to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Complies with JEDEC standard no. 8-1A
- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V.

DESCRIPTION

The 74LVC06A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 to 5 V environment.

The 74LVC06A provides six inverting buffers.

The outputs of the 74LVC06A are open drain and can be connected to other open-drain outputs to implement active-LOW wired-OR or active-HIGH wired-AND functions.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $t_r = t_f \leq 2.5\text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PLZ}/t_{PZL}	propagation delay nA to nY	$C_L = 50\text{ pF}$; $V_{CC} = 3.3\text{ V}$	2.3	ns
C_i	input capacitance		5.0	pF
C_{PD}	power dissipation capacitance per gate	$V_{CC} = 3.3\text{ V}$; notes 1 and 2	8.0	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_i = \text{GND}$ to V_{CC} .

FUNCTION TABLE

See note 1.

INPUT	OUTPUT
nA	nY
L	Z
H	L

Note

1. H = HIGH voltage level;
L = LOW voltage level;
Z = high-impedance OFF-state.

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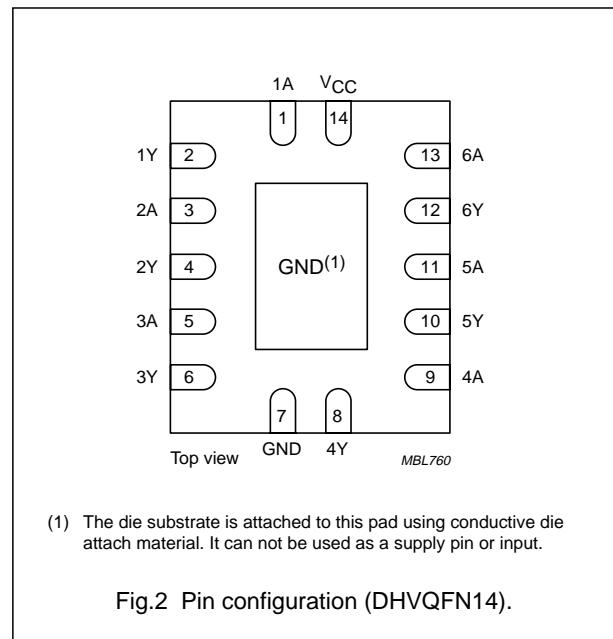
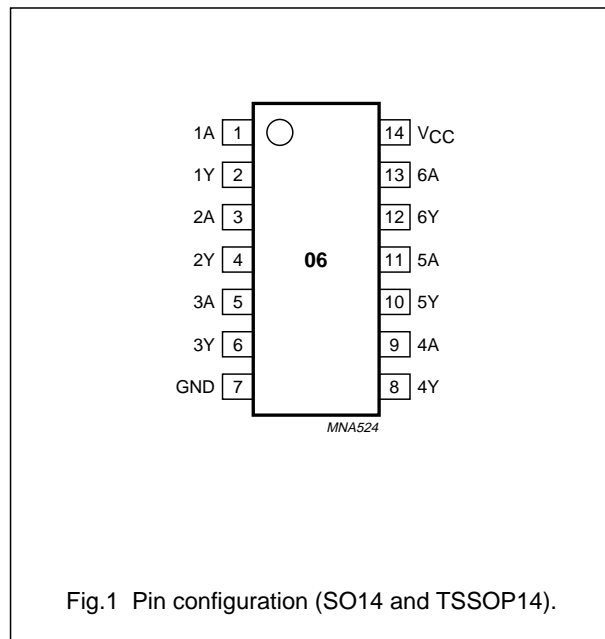
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ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74LVC06AD	-40 to +125 °C	14	SO14	plastic	SOT108-1
74LVC06APW	-40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74LVC06ABQ	-40 to +125 °C	14	DHVQFN14	plastic	SOT762-1

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1Y	data output
3	2A	data input
4	2Y	data output
5	3A	data input
6	3Y	data output
7	GND	ground (0 V)
8	4Y	data output
9	4A	data input
10	5Y	data output
11	5A	data input
12	6Y	data output
13	6A	data input
14	V _{CC}	supply voltage



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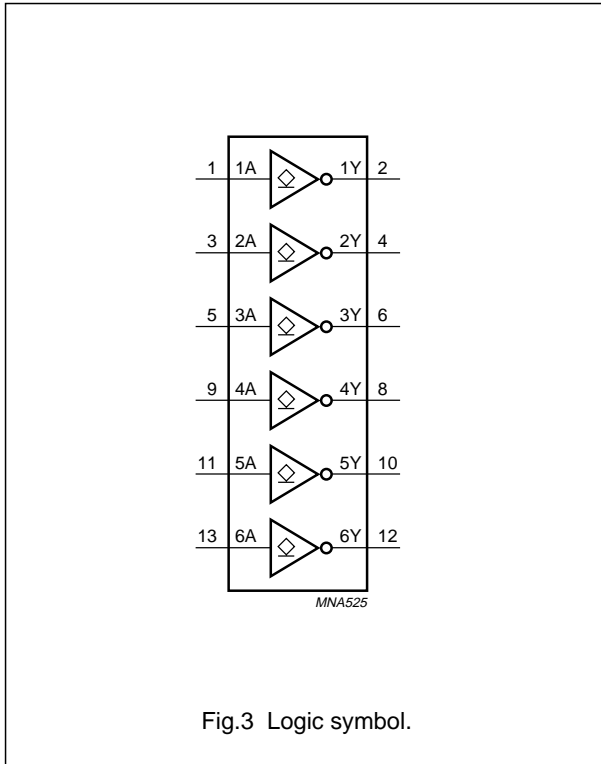


Fig.3 Logic symbol.

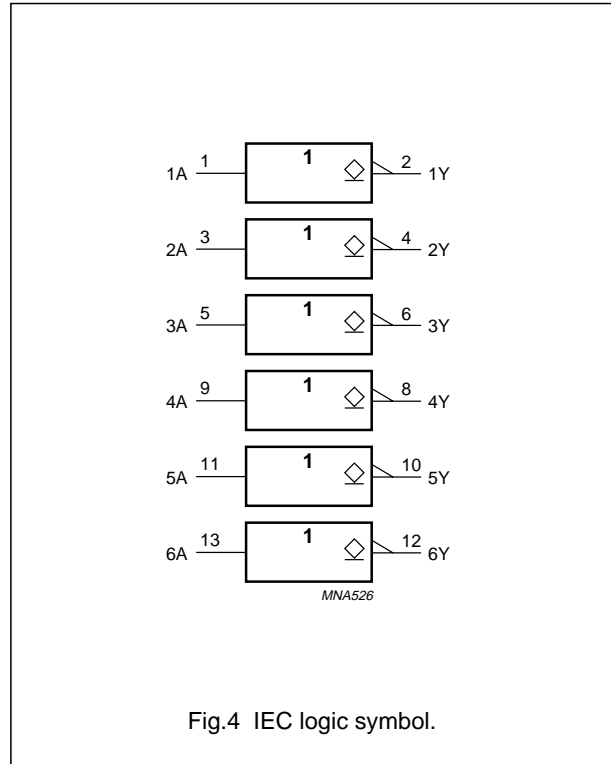


Fig.4 IEC logic symbol.

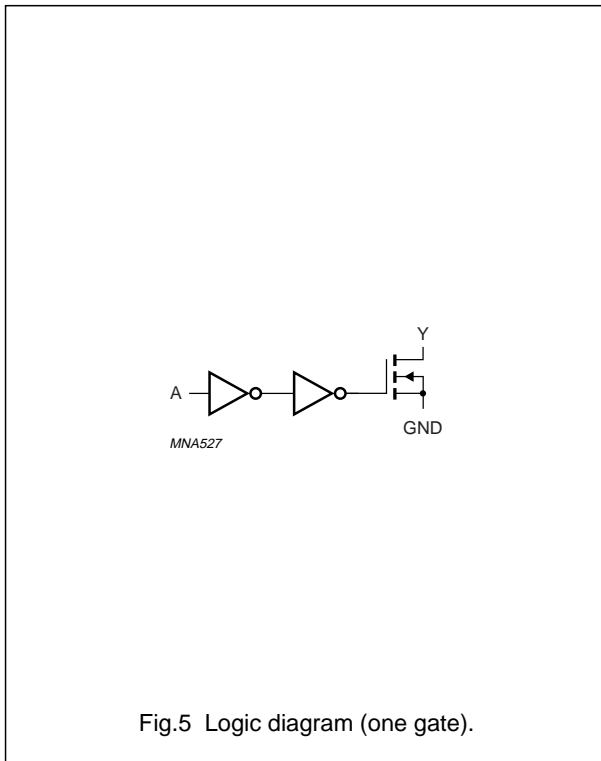


Fig.5 Logic diagram (one gate).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		1.65	5.5	V
V_I	input voltage		0	5.5	V
V_O	output voltage	active mode	0	5.5	V
		high-impedance mode	0	5.5	V
T_{amb}	operating ambient temperature		-40	+125	°C
t_r, t_f	input rise and fall ratios	$V_{CC} = 1.65$ to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ to 5.5 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input diode current	$V_I < 0$	-	-50	mA
V_I	input voltage	note 1	-0.5	+6.5	V
I_{OK}	output clamping diode current	$V_O < 0$	-	-50	mA
V_O	output voltage	active mode; note 1	-0.5	+6.5	V
		high-impedance mode; note 1	-0.5	+6.5	V
I_O	output source or sink current	$V_O = 0$ to V_{CC}	-	50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	power dissipation	$T_{amb} = -40$ to $+125$ °C; note 2	-	500	mW

Notes

- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SO14 packages: above 70 °C derate linearly with 8 mW/K.
For TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 to +85 °C							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	V _{CC}	–	–	V
			2.3 to 2.7	1.7	–	–	V
			2.7 to 3.6	2.0	–	–	V
			4.5 to 5.5	0.7 × V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	–	–	GND	V
			2.3 to 2.7	–	–	0.7	V
			2.7 to 3.6	–	–	0.8	V
			4.5 to 5.5	–	–	0.30 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 100 µA I _O = 4 mA I _O = 8 mA I _O = 12 mA I _O = 24 mA I _O = 32 mA	1.65 to 5.5	–	–	0.20	V
			1.65	–	–	0.45	V
			2.3	–	–	0.3	V
			2.7	–	–	0.4	V
			3.0	–	–	0.55	V
			4.5	–	–	0.55	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	1.65 to 5.5	–	±0.1	±5	µA
I _{OZ}	output leakage current	V _I = V _{IH} ; V _O = 5.5 V or GND	1.65 to 5.5	–	0.1	±10	µA
I _{off}	power-off leakage current	V _I or V _O = 5.5 V	0	–	±0.1	±10	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	0.1	10	µA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} – 0.6 V; I _O = 0	2.3 to 5.5	–	5	500	µA
T_{amb} = -40 to +125 °C							
V _{IH}	HIGH-level input voltage		1.65 to 1.95	0.65 × V _{CC}	–	–	V
			2.3 to 2.7	1.7	–	–	V
			2.7 to 3.6	2.0	–	–	V
			4.5 to 5.5	0.7 × V _{CC}	–	–	V
V _{IL}	LOW-level input voltage		1.65 to 1.95	–	–	0.35 × V _{CC}	V
			2.3 to 2.7	–	–	0.7	V
			2.7 to 3.6	–	–	0.8	V
			4.5 to 5.5	–	–	0.30 × V _{CC}	V

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}	1.65 to 5.5	–	–	0.20	V
		I _O = 100 μA	1.65	–	–	0.45	V
		I _O = 4 mA	2.3	–	–	0.3	V
		I _O = 8 mA	2.7	–	–	0.4	V
		I _O = 24 mA	3.0	–	–	0.55	V
		I _O = 32 mA	4.5	–	–	0.55	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	1.65 to 5.5	–	–	±5	μA
I _{OZ}	output leakage current	V _I = V _{IH} ; V _O = 5.5 V or GND	1.65 to 5.5	–	–	±10	μA
I _{off}	power-off leakage current	V _I or V _O = 5.5 V	0	–	–	±10	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	5.5	–	–	10	μA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} – 0.6 V; I _O = 0	2.3 to 5.5	–	–	500	μA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

AC CHARACTERISTICS

GND = 0 V; t_r = t_f ≤ 2 ns for V_{CC} ≤ 2.7 V and t_r = t_f ≤ 2.5 ns for V_{CC} ≥ 2.7 V.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = –40 to +85 °C; note 1							
t _{PLZ} /t _{PZL}	propagation delay nA to nY	see Figs 6 and 7	1.65 to 1.95	–	2.9	–	ns
			2.3 to 2.7	0.5	1.8	3.1	ns
			2.7	0.5	2.5	3.9	ns
			3.0 to 3.6	0.5	2.3 ⁽²⁾	3.7	ns
			4.5 to 5.5	0.5	1.7	3.4	ns
T_{amb} = –40 to +125 °C							
t _{PLZ} /t _{PZL}	propagation delay nA to nY	see Figs 6 and 7	1.65 to 1.95	–	–	–	ns
			2.3 to 2.7	0.5	–	4.0	ns
			2.7	0.5	–	5.0	ns
			3.0 to 3.6	0.5	–	5.0	ns
			4.5 to 5.5	0.5	–	4.5	ns

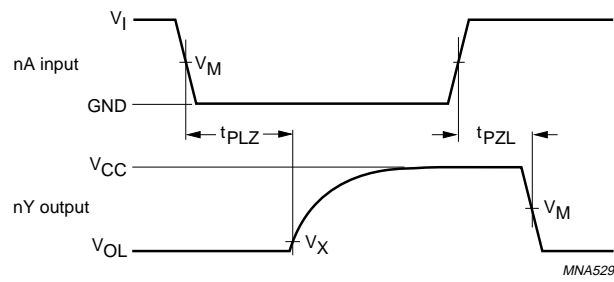
Notes

- All typical values are measured at T_{amb} = 25 °C.
- Typical value is measured at V_{CC} = 3.3 V.

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AC WAVEFORMS

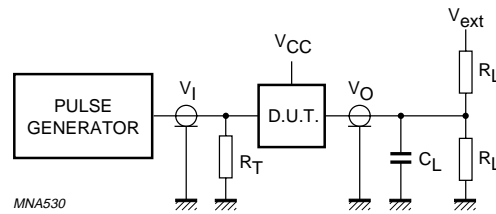


V_{CC}	V_M	V_X
$< 2.7 \text{ V}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15 \text{ V}$
$\geq 2.7 \text{ to } 3.6 \text{ V}$	1.5 V	$V_{OL} + 0.3 \text{ V}$
$\geq 4.5 \text{ to } 5.5 \text{ V}$	$0.5 \times V_{CC}$	$V_{OL} + 0.3 \text{ V}$

Fig.6 The input nA to output nY propagation delays.

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V_{CC}	V_{ext}	V_I	C_L	R_L
1.65 to 1.95 V	$2 \times V_{CC}$	V_{CC}	30 pF	1 k Ω
2.3 to 2.7 V	$2 \times V_{CC}$	V_{CC}	30 pF	500 Ω
2.7 V	6 V	2.7 V	50 pF	500 Ω
3.0 to 3.6 V	6 V	2.7 V	50 pF	500 Ω
4.5 to 5.5 V	$2 \times V_{CC}$	V_{CC}	50 pF	500 Ω

Definitions for test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.7 Load circuitry for switching times.

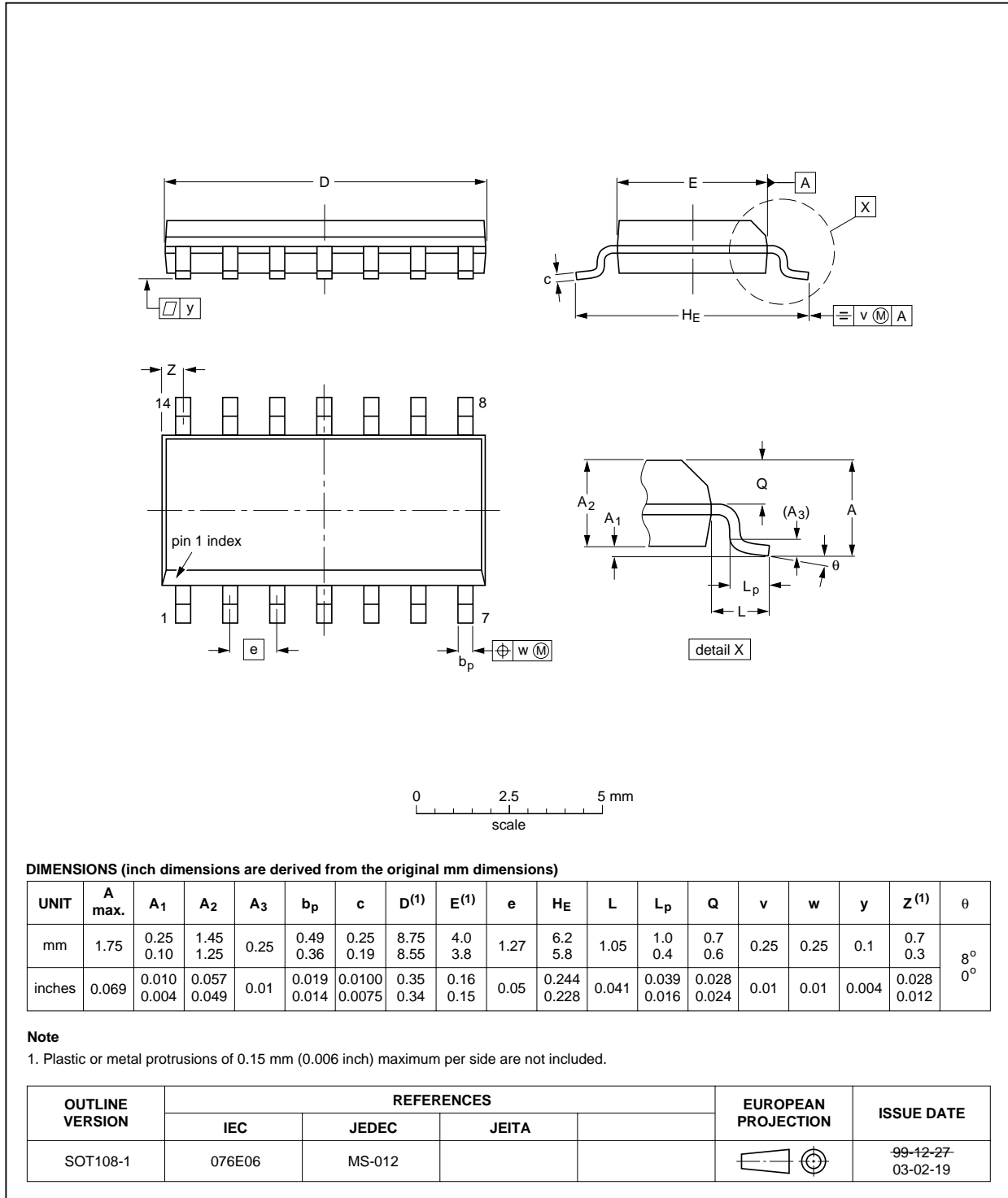
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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

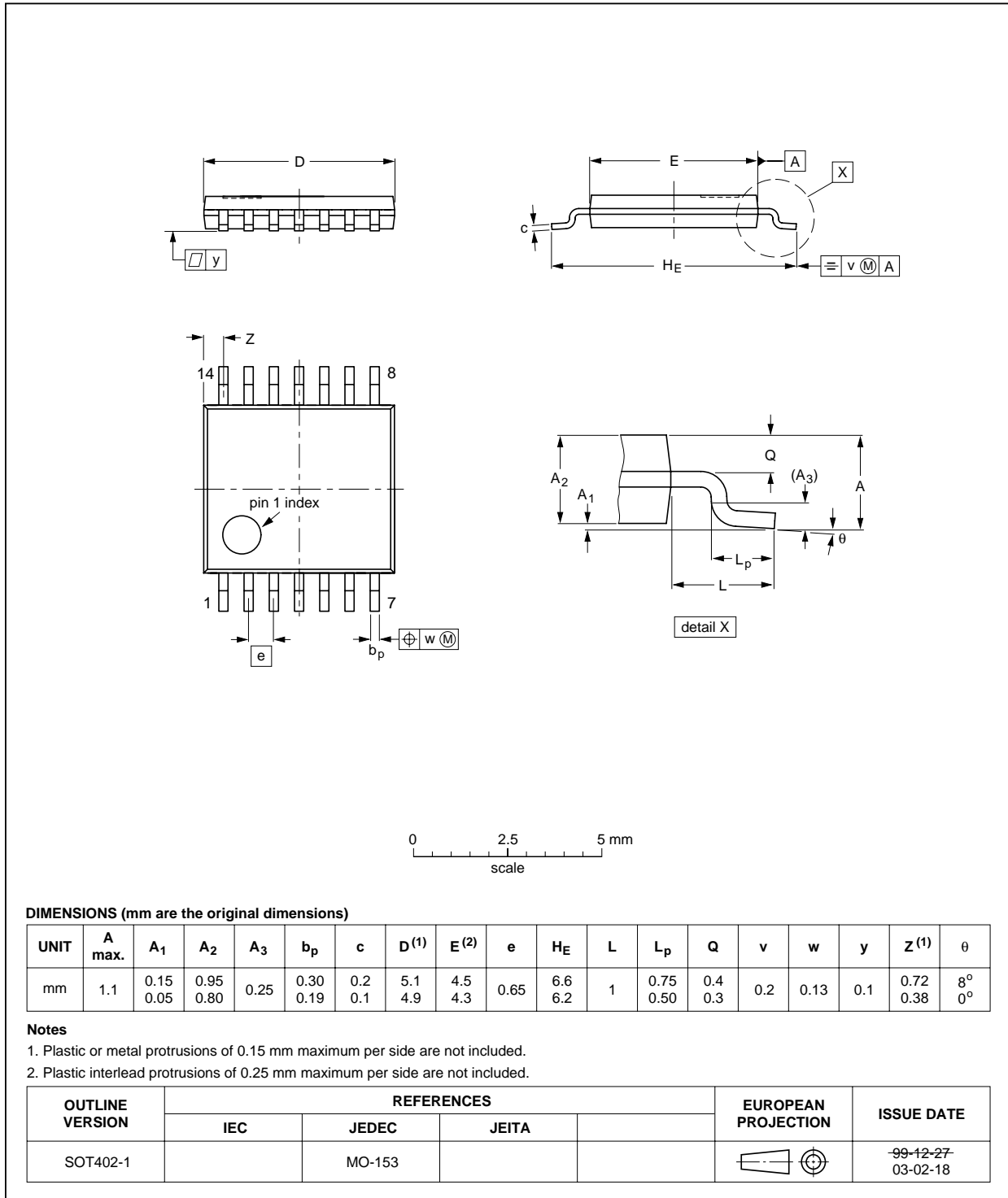


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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A _{max.}	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

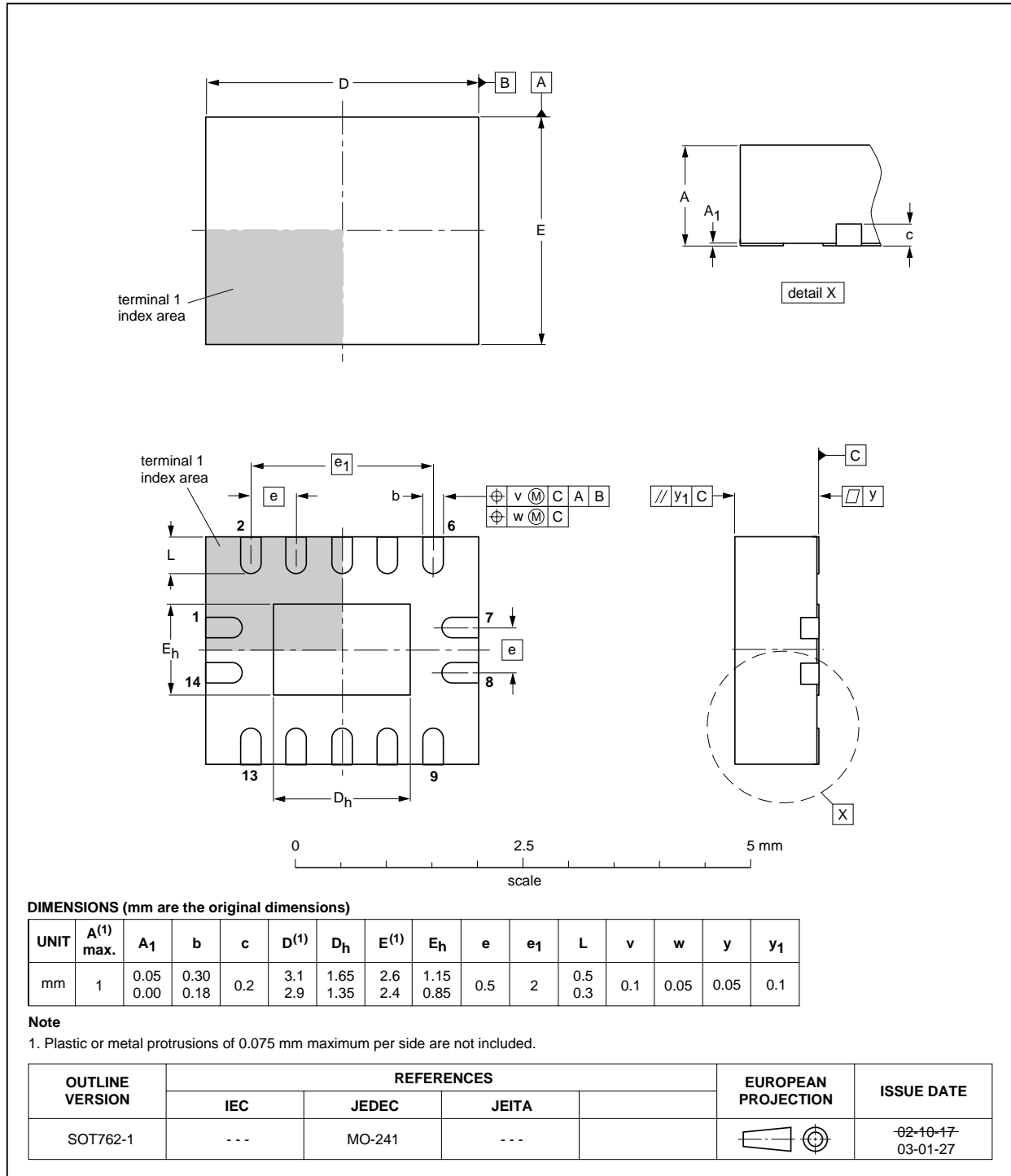
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT402-1		MO-153				99-12-27 03-02-18

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1



Hex inverter with open-drain outputs

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LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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